Electric and magnetic properties of titanium-cobalt-oxide single crystals produced by floating zone melting with light heating

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Single crystals of spinel Co_2TiO_4 , Co_7IiO_3 of ilmenite structure and pseudobrookite $\text{Co}_7\text{Ii}_2\text{O}_5$ were grown by means of zone melting equipment URN-2-ZM. The growth processes were performed in an air atmosphere with a speed ~10 mm/h and a final annealing of the crystal at temperature of 1250 °C. Co_2TiO_4 and $\text{Co}_7\text{Ii}_2\text{O}_5$ crystals were obtained with a diameter of 12–15 mm and length up to 60 mm, being free of any other phase inclusions and cracks. However, in the Co_7Ii_3 crystals some controversial features were found: x-ray Laue analysis indicated high-structure perfection while an electronic microscopy revealed small amount of second phase inclusions in contradiction to known phase diagram of this system. Electrical and magnetic properties of grown Co_7Ti_3 and Co_7Ii_3 single crystals were studied. Semiconducting behavior of the Co_7Ti_3 was established with the energy gap of ~1.3 eV. No magnetic anisotropy was found in the cubic Co_7Ti_3 single crystals showing a magnetic behavior similar to polycrystals. The rhombohedral Co_7Ii_3 crystals revealed a magnetic behavior of an easy plane antiferromagnet with a significant anisotropy of the transverse magnetic susceptibilities along and perpendicular to the trigonal c axis.

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1. Introduction

The cobalt titanates Co₂TiO₄, CoTiO₃, and CoTi₂O₅ are a promising class of materials with many possible applications among others as new magnetodielectric materials. Lately a noticeable increase of interest for investigations of magnetic, electrical, optical properties of various Co-containing oxide compounds occurs [1–4]. But the most of physical investigations of cobalt titanates were carried out using of polycrystals or thin films. Only in few papers single crystals were investigated. In particular, highly crystalline and idiomorphic CoTiO₃ single crystals with a well-defined polyhedral morphology were grown by a common flux method in Ref. 5. Pseudobrookite compounds CoTi₂O₅, MgTi₂O₅, and FeTi₂O₅ were prepared by solid state reactions and single crystals of quenched samples were examined by x-ray in Ref. 6.

Possible difficulty of crystal growth from the melt is connected with complicated structure of P-T-X phase dia-

gram of the Co–Ti–O system [7] (Fig. 1). In addition to the CoO and TiO₂ compounds, three cobalt titanates Co₂TiO₄, CoTiO₃, and CoTi₂O₅ also exist. The two former titanates melt congruently at 1562 and 1463 °C, respectively, while CoTi₂O₅ melts incongruently at 1482 °C [8]. Results of modern researches of these systems [9] show that cobalt ion valence can be change with Co₃O₄ oxide formation and depends on the temperature and the ambient gas. So real phase equilibrium in this system includes such components as TiO₂, CoO, Co₃O₄, CoTiO₃, Co₂TiO₄, and CoTi₂O₅. The stabilization of Co₂TiO₄ structure and others as a single phase is more expected at high temperature and this high-temperatures state is quenched by rather quick cooling of the crystal.

The purpose of this work consisted in crystal growth of cobalt titanates because these crystals represent interest as the objects of investigation of lattice dynamic and electronic structure of spinels [10], as possible substrate materials

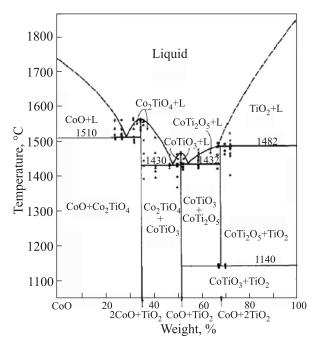


Fig. 1. Phase diagram for the system CoO–TiO₂ in air [7].

for magnetic ferrospinel film deposition (Co₂TiO₄), as materials with expected notable magnetodielectric properties (CoTiO₃) [11] and investigation of peculiarities ions ordering in pseudobrookite structure (CoTi₂O₅) [6]. The use of single crystals permits to investigate anisotropic properties of materials, to study electric transport features more precisely and perhaps to find and study magnetoelectric phenomena in these materials.

The floating zone melting method of crystal growth with light heating provides conditions for obtaining of cobalt titanate single-phase crystals. If the high-temperature annealing of single crystals in growing process is used, it is possible to obtain almost perfect crystals.

2. Experimental details

The single crystals have been grown by crucibleless floating zone (FZ) melting method with light heating by means of URN-2-ZM equipment [11]. Cobalt and titanium oxides of chemicals 4N purity were used as starting materials. Oxide mixtures corresponding to the stoichiometric Co₂TiO₄, CoTiO₃, and CoTi₂O₅ compositions were used as starting compounds to produce the feed rods for floating zone by common ceramic technology.

The technological conditions of Co_2TiO_4 , $CoTiO_3$, and $CoTi_2O_5$ single-crystal growth by FZ were as follows (almost the same for all compositions):

- Linear crystallization speed was 5–10 mm/h;
- Rotation frequency of crystal and feed rod were 40 and 1 r/min, respectively;
- For Co_2TiO_4 x-ray oriented single crystalline seeds about $3\times3\times12$ mm in size cut from magnetic ferrospinel crystals or from preliminary grown Co–Ti spinel crystals were used;



Fig. 2. Single crystal of Co₂TiO₄.

- For CoTiO₃ and CoTi₂O₅ crystal growth the fragments of early grown crystals were used as a seed crystal;
- The growth was performed in an air atmosphere or in a flow of oxygen or argon;
- Annealing furnace temperature in growth processing was equal 1250 °C;
- Using FZ method single crystals were obtained with a diameter of 12–15 mm and length up to 60 mm (Fig. 2).

The diagnostics of the samples were performed by diffraction methods (x-ray phase analysis and Laue method). Microstructure of the samples was investigated using JSM-5910LV (JEOL) scanning electron microscope in Z-contrast backscattered electrons mode. Determination of the chemical composition was carried out by means of x-ray energy dispersive analysis using AZtecENERGY (Oxford Instruments) analytical system. The x-ray analysis (XRD) of the samples was conducted using Bruker D2 Phaser powder x-ray diffractometer with Cu- K_{α} radiation. Processing of the results and the phase analysis of samples was performed using software packages DIFFRAC (EVA and TOPAS 4.2.0.2). Laue images have been obtained with digital apparatus of Photonic Science.

The magnetic properties were studied in static magnetic fields up to 5 T at temperatures from 2 to 340 K by the SQUID magnetometer (Quantum Design). The electrotransport properties were measured by means of Keithley 6517A electrometer with silver paste electrical contacts.

3. X-ray and microstructure characterization of the grown crystals

According to the phase diagram of the CoO-TiO₂ system (Fig. 1) there should not be a problem to grow from the melt the crystals of the Co₂TiO₄ and CoTiO₃ compounds due to their congruent melting. On the other hand, the CoTi₂O₅ compound suffering an incongruent melting requires special conditions for a good crystal grown. Actually, very perfect Co₂TiO₄ and pseudobrookite CoTi₂O₅ crystals were grown for used FZ growth parameters that was confirmed by x-ray Laue patterns (Fig. 3), powder

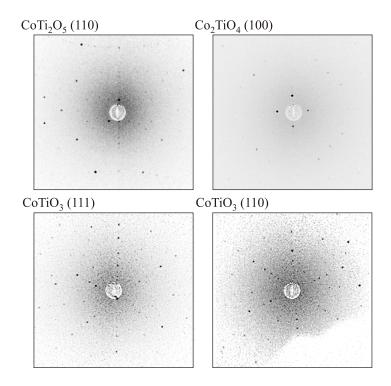


Fig. 3. Laue patterns of the grown crystals Co–Ti oxide compounds.

(Fig. 4) and single-crystal (Fig. 5) diffraction measurements. Small angular width (~0.08–0.1°) of representing x-ray reflections for polished cross sections of the grown single crystals confirms their high quality and low values of internal stress distortions (Fig. 5).

In spite of good Laue pattern we found that CoTiO₃ crystals contain small amount of second phase inclusion (Fig. 6). This is connected with a complicated behavior of the compounds at high temperatures [8] and high temperature gradients in cross section of melts at a growth interface. It results in a decomposition of main CoTiO₃ compound and appearance of two types of secondary phases: Co₂TiO₄ and CoTi₂O₅. The Co₂TiO₄ secondary phase precipitates at a periphery of a crystal cross section while CoTi₂O₅ one precipitates in a central part. The volume of

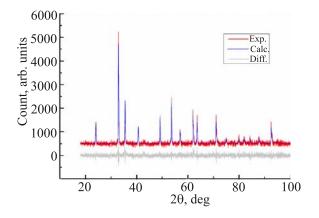


Fig. 4. (Color online) Refined x-ray diffraction pattern for CoTiO_3 powder.

second phases is less 3% and is not reflected in x-ray measuring data. The quality of the Co₂TiO₄ and CoTi₂O₅ crystals almost do not depend on a gas ambient during a crystal growth. The amount of the secondary phases decreases but does not disappear completely during the CoTiO₃ growth in an oxygen flow. This observation con-

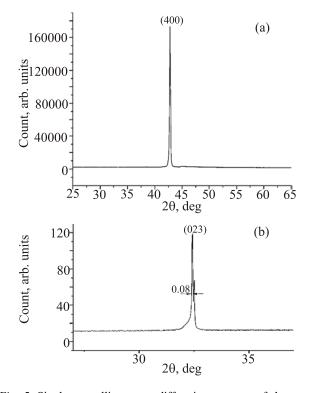


Fig. 5. Single crystalline x-ray diffraction patterns of the cross section of Co_2TiO_4 (a) and $CoTi_2O_5$ (b) single crystals.

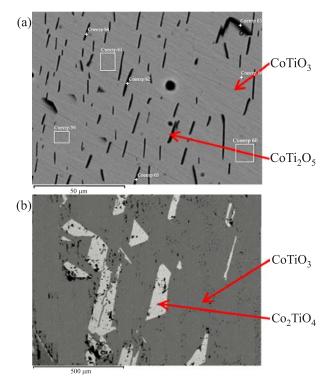


Fig. 6. SEM backscattered electron image (Z-contrast) in peripheral (a) and central (b) regions of the CoTiO₃, grown in nonoptimal conditions.

tradicts to the phase diagram of the system according to which this compound melts congruently (Fig. 1).

The refined unit-cell parameters of the grown crystals are presented in Table 1 which demonstrates a good agreement with corresponding literature data for these compounds.

4. Physical properties of crystals

4.1. Electrical resistivity of Co₂TiO₄

As can be seen from the Fig. 7(a), the sample has enough high resistivity $\sim 10^9$ Ohm-cm at room temperature and close to ohmic contacts. With decreasing temperature the resistance grows exponentially versus 1/T (Fig. 7(b)) and gives the forbidden zone (bandgap) value of ~ 1.3 eV. Below ~ 200 K the resistance of crystal becomes very high as in good isolators and its measurement becomes impossible. We also tried to find some manifestations of magnetoelectric effects in the temperature and magnetic field

dependences of pyroelectric current along [100] axis in magnetic field **H** perpendicular to electric field **E** but these attempts were failed.

4.2. Magnetic properties of Co₂TiO₄

Results of our magnetic measurement are in a good agreement with data of Ref. 1. The found values of ferrimagnetic ordering temperature (48 \pm 1) K and compensation point (30.5 \pm 1) K are close to the corresponding values of $T_N \sim 47.8$ K and $T_{\rm comp} \sim 32$ K from Ref. 1. Temperature dependences of magnetization at different magnetic fields and magnetization curves at different temperatures also practically coincided with the data obtained in [1] (Figs. 8–10). However we obtained another values of the asymptotic Curie point T_a , and the effective magnetic moment μ_{eff} determined from the temperature dependence of the inverse magnetic susceptibility (Fig. 9), namely, $T_a = (-150 \pm 2)$ K and $\mu_{eff} = (7.0 \pm 0.1) \, \mu_B$ according to our data in contrast to $T_a = -125$ K and $\mu_{eff} = 6.5 \mu_B$ of Ref. 1. Such discrepancy for the values of the effective moment provokes doubts for the reliability of the Co ion moments for different crystallographic positions found in Ref. 1.

Magnetization curves linearly depend on magnetic field H at the compensation point 30 K, but they exhibit hysteresis loops below and above this point (Figs. 10(a)–(c)). Near Curie point the hysteresis becomes narrow and disappears in paramagnetic state (Figs. 10(c), (d)). Most importantly, we haven't found noticeable magnetic anisotropy along different crystallographic directions of the cubic crystal: <100>, <110>, and <111> in any magnetic state. Possible explanation of this phenomenon can be connected with low anisotropy above and near T_N and appearance of a spinglass state at low temperatures.

4.3. Magnetic properties of CoTiO₃

In contrast to the almost isotropic Co₂TiO₄ the CoTiO₃ crystal, possessing rhombohedral (R3) ilmenite structure, exhibits a significant anisotropy of the magnetic characteristics up to temperatures of ~ 350 K (Fig. 11) in a good agreement with Ref. 12. The dc magnetic susceptibility $\chi_{dc} = \sigma/H$ along the trigonal c axis is noticeably smaller than that in the basis plane, within which the magnetic anisotropy is small. The Néel temperature $T_N = 37-38$ K clearly emerges as a maximum in the temperature

Table 1. Unit-cell parameters in comparison with literature data

Composition	a, Å	b, Å	c, Å	Space group	JCPDS, card No
Co ₂ TiO ₄	8.4570(3)			Fd3m	Refined
	8.434				39-1410
CoTiO ₃	5.0662(6)		13.916(2)	R3	Refined
	5.056		13.91		77-1356
CoTi ₂ O ₅	3.7319(7)	9.721(2)	10.094(3)	Стст	Refined
	3.732	9.718	10.06		76-1600

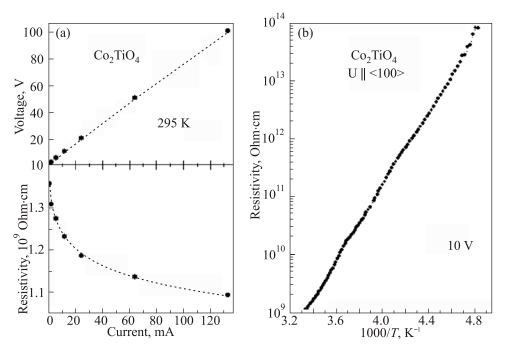


Fig. 7. Electric properties of the Co_2TiO_3 crystals: (a) Current-voltage characteristic (top) and dependence of the electric resistivity on current along the <100> crystallographic direction at T = 295 K; (b) Temperature dependence of electrical resistivity measured along the <100> axis in the applied voltage 10 V.

dependence of $\chi_{dc}(T)$. A blurred nature of the maximum for the $\chi_{dc}(T)$ for $\mathbf{H} \| \mathbf{c}$ is associated with the presence of impurity phases of Co₂TiO₄ and CoTi₂O₅ which also possess anomalies of magnetic properties at similar temperatures. Magnetization curves along c axis are linear up to 5 T at all temperatures from 1.9 to 340 K, however, in a perpendicular direction (i.e., in the basis plane) the $\sigma(H)$

curves become significantly nonlinear in the fields of 3–4 T at $T < T_N$ thus indicating on a rotation of the Co²⁺ magnetic moments in the basal plane to the direction perpendicular to the applied field (inset in Fig. 11). In a whole CoTiO₃ shows up properties of an easy-plane antiferromagnet possessing a significant anisotropy of the transverse magnetic susceptibilities along and perpendicular to the c axis which

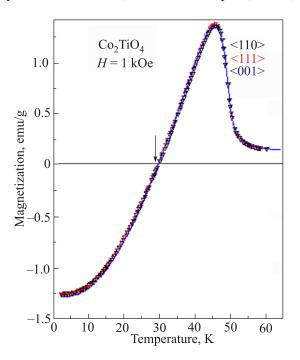


Fig. 8. (Color online) Temperature dependences of magnetization measured in the field of 1 kOe along different crystallographic directions.

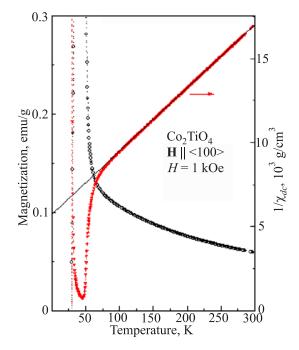


Fig. 9. (Color online) Temperature dependences of the magnetization along <100> axis in H=1 kOe (left scale) and reverse magnetic susceptibility (right scale).

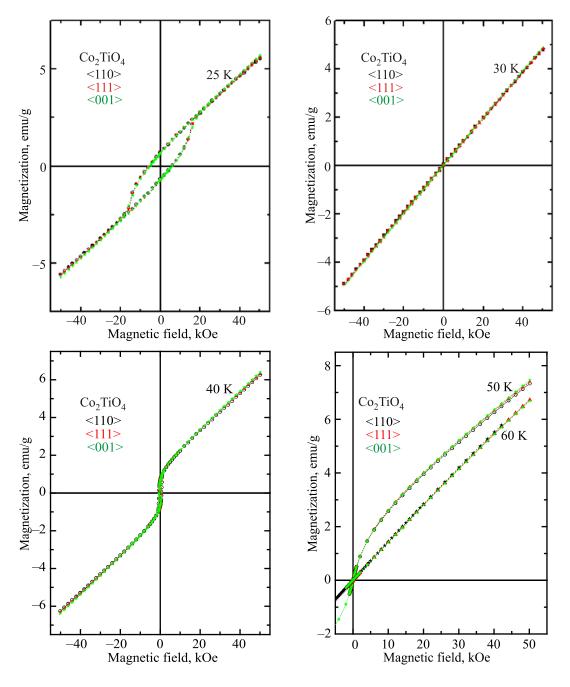


Fig. 10. (Color online) Magnetization curves of Co_2TiO_3 single crystals along <110>, <111>, <001> pseudocubic crystallographic directions and various temperatures: (a) T = 25 K, (b) 30 K, (c) 40 K and (d) 50 and 60 K.

origin could be related to a noticeable anisotropy of g factor of the Co^{2+} ions with a strong spin-orbital coupling.

5. Conclusion

Single crystals of titanium cobaltites Co_2TiO_4 , $CoTiO_3$, and $CoTi_2O_5$ have been grown for the first time by floating zone melting with light heating in different gas ambient. Their crystal structure parameters were investigated by x-ray diffraction and electron microscopy. It was established that rather perfect Co_2TiO_4 and $CoTi_2O_5$ single crystals can be grown in air with further annealing at 1250 °C. However,

independently of gas ambient the CoTiO₃ crystals contain precipitation of second phases in amount of $\sim 1\%$, representing either CoTi₂O₅ in the central part of a boule or Co₂TiO₄ in its periphery part.

 Co_2TiO_4 exhibits semiconducting behavior with the energy gap of ~ 1.3 eV. No magnetic anisotropy was found in Co_2TiO_4 single crystals in a wide temperature range and their magnetic behavior was similar to polycrystalline samples. In spite of presence of a small amount of impurity phases, temperature and field dependences of magnetization in the grown $CoTiO_3$ crystal adequately reflect the be-

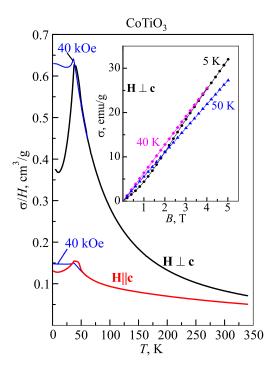


Fig. 11. (Color online) Temperature dependences of dc magnetic susceptibility measured for 1 kOe along and perpendicular to the trigonal c axis. In the low-temperature region the data for H=40 kOe are also presented. The inset shows the magnetization curves at different temperatures at $\mathbf{H} \perp \mathbf{c}$.

havior of pure CoTiO₃ easy-plane antiferromagnetic phase below 37 K exhibiting a remarkable anisotropy of the transverse magnetic susceptibilities.

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